

Supplementary Information

Facile synthesis and stable lithium storage performances of Sn- sandwiched nanoparticles as a high capacity anode material for rechargeable Li batteries

Zhongxue Chen^a, Yuliang Cao,^{*ab} Jiangfeng Qian,^a Xinpeng Ai^a and Hanxi Yang^{*a}

^a Hubei Key Lab. of Electrochemical Power Sources, College of Chemistry and Molecular Science,

Wuhan University Wuhan 430072, (P. R. China). Tel: 86-027-68754526;

E-mail: hxyang@whu.edu.cn

^b Pacific Northwest National Laboratory, Richland Washington 99352, USA.

E-mail: ylcao@whu.edu.cn

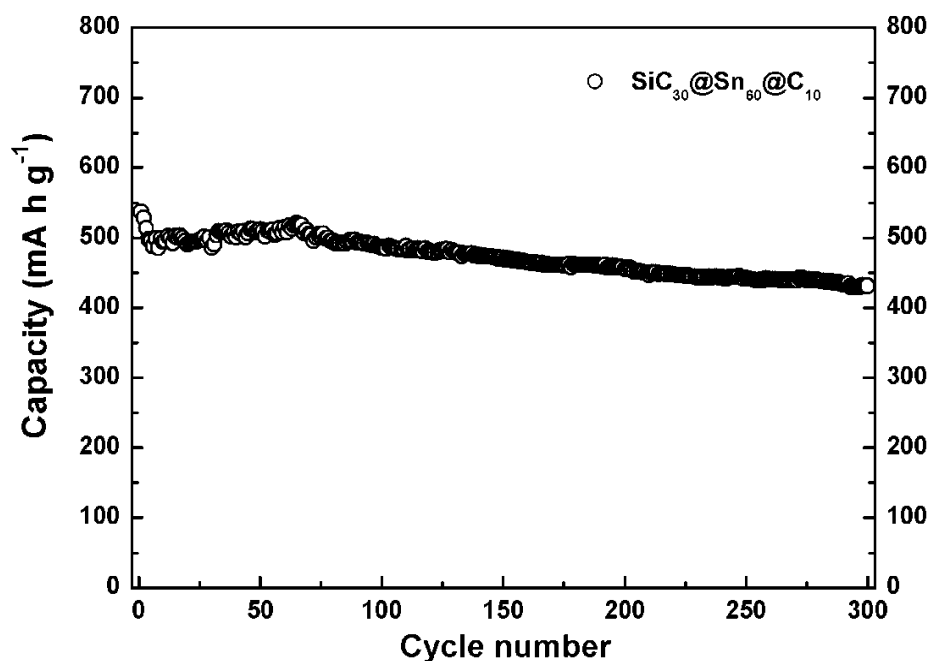


Fig. S1 Electrochemical cyclic performance of the SiC₃₀@Sn₆₀@C₁₀ composite at a constant current of 100 mA g⁻¹. The composite exhibits a reversible capacity of 431 mA h g⁻¹ up to 300 cycles (80.3% of the initial capacity).

Table S1 Comparison of the electrochemical performance of the Sn composite in this work with those reported in the literatures

Ref.	Sample	Method	Testing voltage window (vs. Li ⁺ /Li)	Initial coulombic efficiency (%)	Initial reversible capacity	Capacity retention after cycling	Capacity attenuation rate (%)
						mA h g ⁻¹	
Ours	SiC ₃₀ @Sn ₆₀ @C ₁₀	multiBall milling	0.01~1.5V	50	537	490(100 th) 431(300 th)	0.087 0.066
[36]	Sn-C	Sol-gel& calcination	0.02~1.5V	~40	450	~450(100 th)	0
[38]	Sn@C	Hydrothermal synthesis	0.005~2.0 V		~620	311(200 th)	0.25
[35]	Sn-C	Sol-gel& calcination	0.01~1.5V	~70	350	~500(200 th)	0
[44]	Sn@C	Hydrothermal synthesis	0~1.5V	86	681	664(50 th)	0.05
[45]	Sn@CNT	CVD method	0.005~3.0 V	67.5	716	~250(80 th)	0.8
	Sn@C@CNT	Solid-state pyrolysis	0.01~3.0V	77.8	526	474(80 th)	0.12
[46]	Sn-Co-C	Ball milling	0.01~1.5V	~64	450	270(100 th)	0.4
[47]	Sn-Co-C	Alloyed mechanically	0.005~1.2 V		~460	~380(100 th)	0.17
[48]	Sn/C	Modified Hummer's method	0~3.0V	64.8	810	508(100 th)	0.37
[31]	SnCo/CNT	Chemical reduction	0.02~1.5V	~58	506	424(30 th)	0.54

References

- 31 Ke, F. S. L. Huang, H. H. Jiang, H. B. Wei, F. Z. Yang and S. G. Sun, *Electrochem. Commun.*, 2007, **9**, 228.
- 35 G. Derrien, J. Hassoun, S. Panero and B. Scrosati, *Adv. Mater.*, 2007, **19**, 2336.
- 36 J. Hassoun, G. Derrien, S. Panero and B. Scrosati, *Adv. Mater.*, 2008, **20**, 3169.
- 38 D. Deng and J. Y. Lee, *Angew. Chem. Int. Ed.*, 2009, **48**, 1660.
- 44 M. J. Noh, Y. J. Kwon, H. J. Lee, J. Cho, Y. J. Kim and M. G. Kim, *Chem. Mater.*, 2005, **17**, 1926.
- 45 Y. Wang, M. H. Wu, Z. Jiao and J. Y. Lee, *Chem. Mater.* 2009, **21**, 3210.
- 46 J. Hassoun, G. Mulas, S. Panero and B. Scrosati, *Electrochem. Commun.* 2007, **9**, 2075.
- 47 P. P. Ferguson, M. L. Martine, R. A. Dunlap and J. R. Dahn, *Electrochim. Acta* 2009, **54**, 4534.

48 G. X. Wang, B. Wang, X. L. Wang, J. S. Park, S. X. Dou, H. J. Ahnb and K. W. Kim, *J.*

Mater. Chem. 2009, **19**, 8378.